

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCXH16652FT

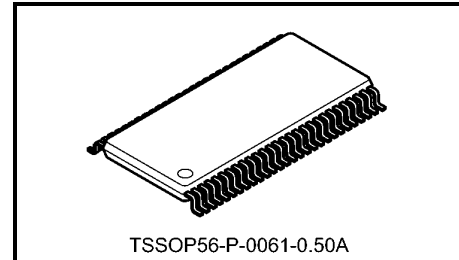
## Low-Voltage 16-Bit Bus Transceiver/Register with Bushold

The TC74VCXH16652FT is a high-performance CMOS 16-bit bus transceiver/register. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is bus transceiver with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the internal registers.

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



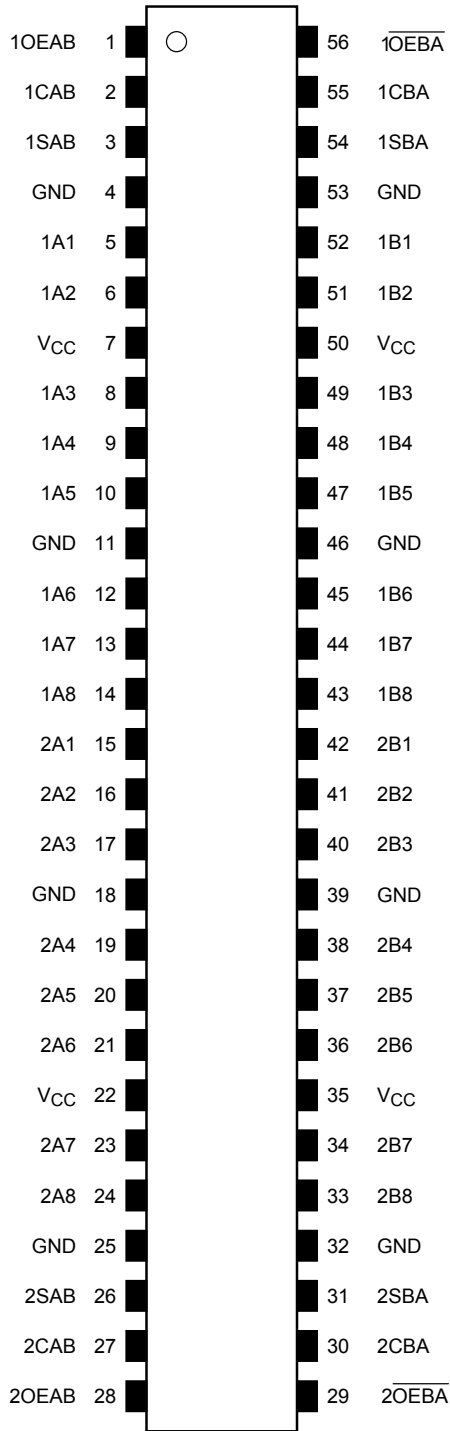
Weight: 0.25 g (typ.)

### Features (Note)

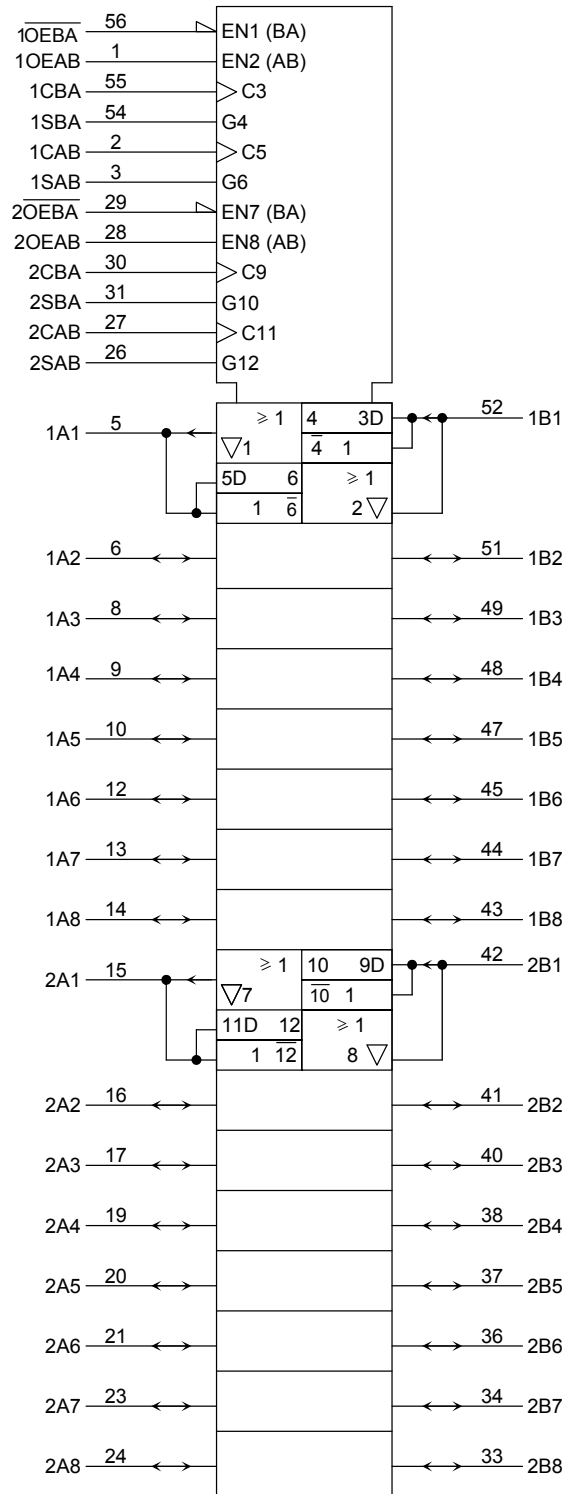
- Low-voltage operation:  $V_{CC} = 1.8$  to  $3.6$  V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation :  $t_{pd} = 2.9$  ns (max) ( $V_{CC} = 3.0$  to  $3.6$  V)  
:  $t_{pd} = 3.5$  ns (max) ( $V_{CC} = 2.3$  to  $2.7$  V)  
:  $t_{pd} = 7.0$  ns (max) ( $V_{CC} = 1.8$  V)
- 3.6-V tolerant control inputs
- Output current:  $I_{OH}/I_{OL} = \pm 24$  mA (min) ( $V_{CC} = 3.0$  V)  
:  $I_{OH}/I_{OL} = \pm 18$  mA (min) ( $V_{CC} = 2.3$  V)  
:  $I_{OH}/I_{OL} = \pm 6$  mA (min) ( $V_{CC} = 1.8$  V)
- Latch-up performance:  $-300$  mA
- ESD performance: Machine model  $\geq \pm 200$  V  
Human body model  $\geq \pm 2000$  V
- Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.







## Pin Assignment (top view)



## IEC Logic Symbol



## Truth Table

Control Inputs						Bus		Function
OEAB	$\overline{\text{OEBA}}$	CAB	CBA	SAB	SBA	A	B	
L	H	X*	X*	X	X	Input Z	Input Z	The output functions of A and B Busses are disabled.
				X	X	X	X	X
H	H	X*	X*	L	X	Input L H	Output L H	The data on the A bus are displayed on the B bus.
			X*	L	X	L H	L H	The data on the A bus are displayed on the B Bus, and are stored into the A storage flip-flops on the rising edge of CAB.
		X*	X*	H	X	X	Qn	The data in the A storage flip-flops are displayed on the B Bus.
			X*	H	X	L H	L H	The data on the A Bus are stored into the A storage flip-flops on the rising edge of CAB, and the stored data propagate directly onto the B Bus.
L	L	X*	X*	X	L	Output L H	Input L H	The data on the B Bus are displayed on the A bus.
		X*		X	L	L H	L H	The data on the B Bus are displayed on the A Bus, and are stored into the B storage flip-flops on the rising edge of CBA.
		X*	X*	X	H	Qn	X	The data in the B storage flip-flops are displayed on the A Bus.
		X*		X	H	L H	L H	The data on the B Bus are stored into the B storage flip-flops on the rising edge of CBA, and the stored data propagate directly onto the A Bus.
H	L	X*	X*	H	H	Output Qn	Output Qn	The data in the A storage flip-flops are displayed on the B Bus, and the data in the B storage flip-flops are displayed on the A.

X: Don't care

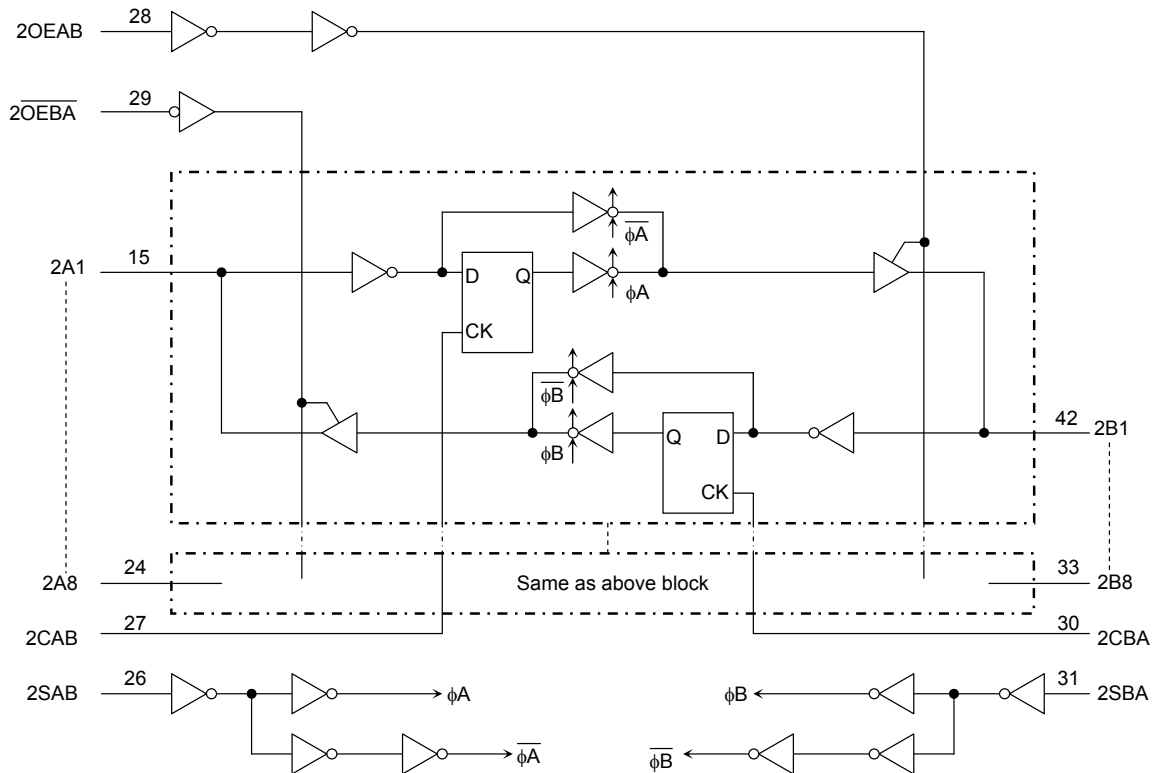
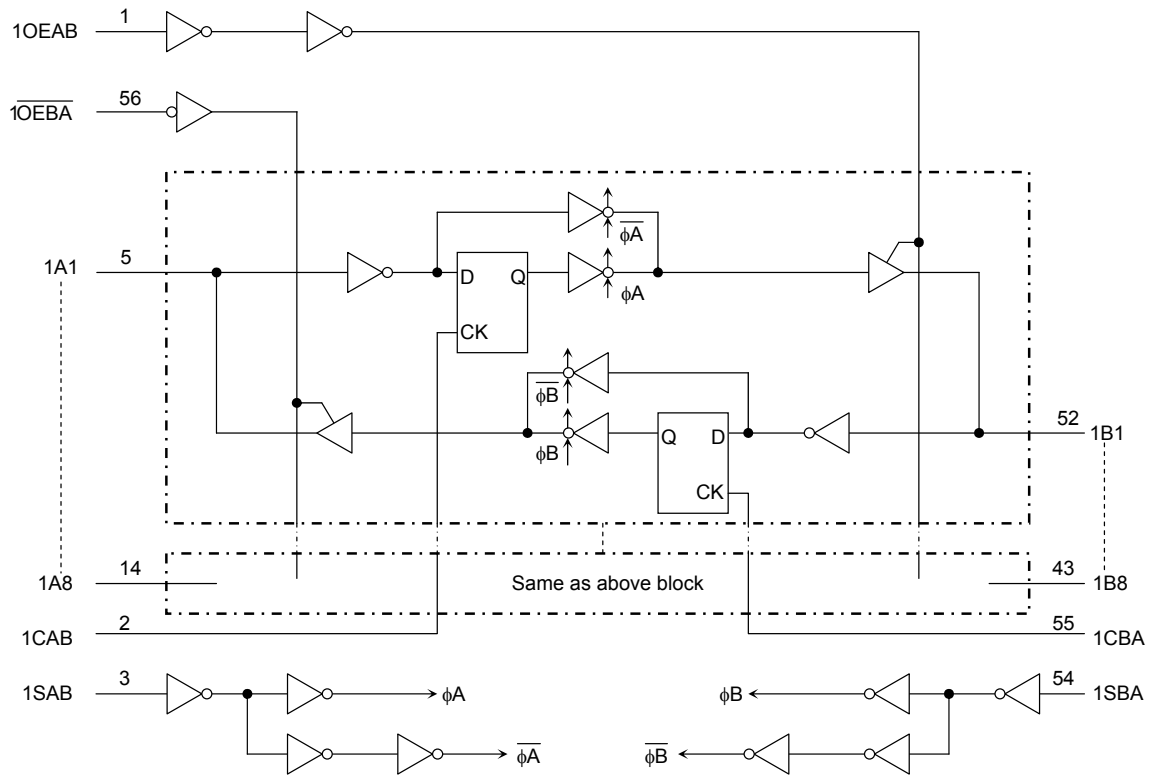
Z: High impedance

Qn: The data stored into the internal flip-flops by most recent low to high transition of the clock inputs.

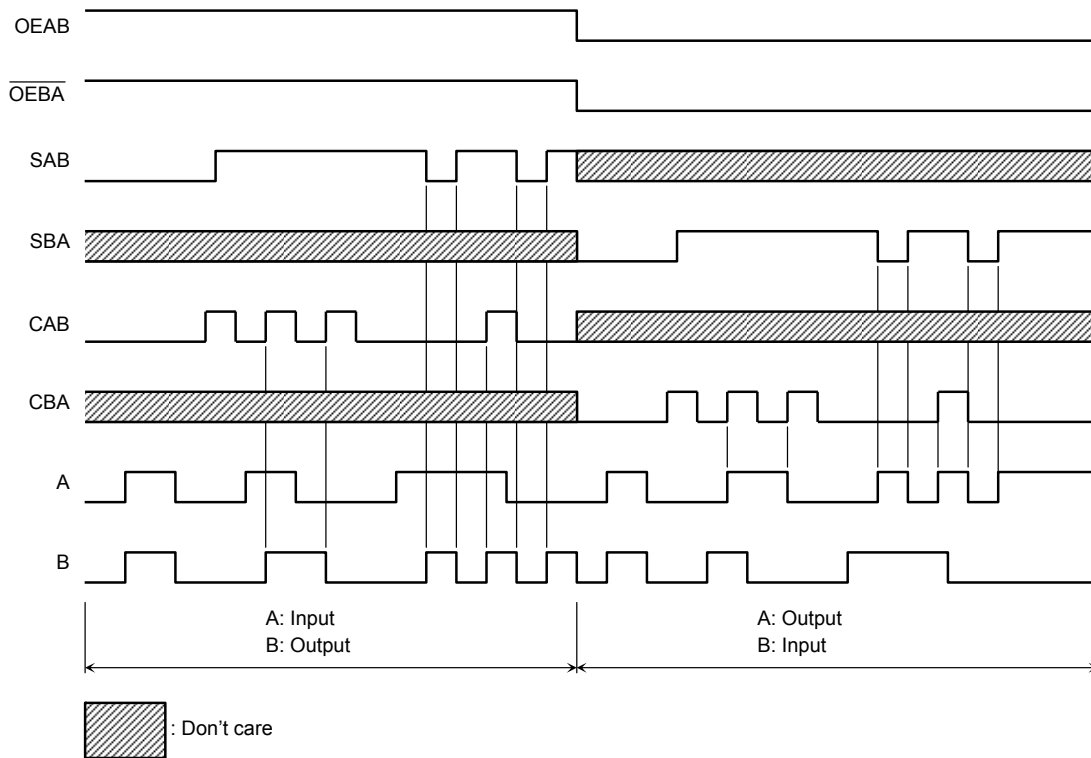
\*: The clocks are not internally gated with either OEAB or  $\overline{\text{OEBA}}$ .

Therefore, data on the A and/or B busses may be clocked into the storage flip-flops at any time.

**System Diagram**



## Timing Chart



## Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit
Power supply voltage		$V_{CC}$	-0.5 to 4.6	V
DC input voltage	(OEAB, OEBA, SAB, SBA, CAB, CBA)	$V_{IN}$	-0.5 to 4.6	V
	(An, Bn)		-0.5 to $V_{CC} + 0.5$ (Note 2)	
DC output voltage	(An, Bn)	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$ (Note 3)	V
Input diode current		$I_{IK}$	-50	mA
Output diode current		$I_{OK}$	$\pm 50$ (Note 4)	mA
Output current		$I_{OUT}$	$\pm 50$	mA
Power dissipation		$P_D$	400	mW
DC $V_{CC}$ /ground current per supply pin		$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage temperature		$T_{stg}$	-65 to 150	$^{\circ}C$

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Operating Ranges (Note 1) (Note 2)

Characteristics		Symbol	Rating	Unit
Power supply voltage		$V_{CC}$	1.8 to 3.6	V
			1.2 to 3.6 (Note 3)	
Input voltage	(OEAB, OEBA, SAB, SBA, CAB, CBA)	$V_{IN}$	-0.3 to 3.6	V
	(An, Bn)		0 to $V_{CC}$ (Note 4)	
Output voltage	(An, Bn)	$V_{OUT}$	0 to $V_{CC}$ (Note 5)	V
Output current		$I_{OH}/I_{OL}$	$\pm 24$ (Note 6)	mA
			$\pm 18$ (Note 7)	
			$\pm 6$ (Note 8)	
Operating temperature		$T_{opr}$	-40 to 85	°C
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 2: Floating or unused control inputs must be held high or low.

Note 3: Data retention only

Note 4: OFF state

Note 5: High or low state

Note 6:  $V_{CC} = 3.0$  to  $3.6$  V

Note 7:  $V_{CC} = 2.3$  to  $2.7$  V

Note 8:  $V_{CC} = 1.8$  V

Note 9:  $V_{IN} = 0.8$  to  $2.0$  V,  $V_{CC} = 3.0$  V

## Electrical Characteristics

### DC Characteristics (Ta = -40 to 85°C, 2.7 V < VCC ≤ 3.6 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.7 to 3.6	2.0	—	V
	L-level	V <sub>IL</sub>	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 18 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current (OEAB, $\overline{\text{OEBA}}$ , SAB, SBA, CAB, CBA)		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	—	±5.0	μA
Bushold input minimum drive hold current		I <sub>I</sub> (HOLD)	V <sub>IN</sub> = 0.8 V		3.0	75	—	μA
			V <sub>IN</sub> = 2.0 V		3.0	-75	—	
Bushold input over-drive current to change state		I <sub>I</sub> (OD)	(Note 1)		3.6	—	450	μA
			(Note 2)		3.6	—	-450	
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	—	±10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	—	20.0	μA
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7 to 3.6	—	750	μA

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

**DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)**

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.3 to 2.7	1.6	—	V
	L-level	V <sub>IL</sub>	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.3	2.0	—	
				I <sub>OH</sub> = -12 mA	2.3	1.8	—	
				I <sub>OH</sub> = -18 mA	2.3	1.7	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3 to 2.7	—	0.2	
				I <sub>OL</sub> = 12 mA	2.3	—	0.4	
I <sub>OL</sub> = 18 mA				2.3	—	0.6		
Input leakage current (OEAB, $\overline{\text{OEBA}}$ , SAB, SBA, CAB, CBA)		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
Bushold input minimum drive hold current		I <sub>I</sub> (HOLD)	V <sub>IN</sub> = 0.7 V		2.3	45	—	μA
			V <sub>IN</sub> = 1.6 V		2.3	-45	—	
Bushold input over-drive current to change state		I <sub>I</sub> (OD)	(Note 1)		2.7	—	300	μA
			(Note 2)		2.7	—	-300	
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		2.3 to 2.7	—	±10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 2.7	—	20.0	μA

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.



**DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)**

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		1.8 to 2.3	0.7 × V <sub>CC</sub>	—	V
	L-level	V <sub>IL</sub>	—		1.8 to 2.3	—	0.2 × V <sub>CC</sub>	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	1.8	1.4	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0.2	
				I <sub>OL</sub> = 6 mA	1.8	—	0.3	
Input leakage current (OEAB, OEBA, SAB, SBA, CAB, CBA)		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8	—	±5.0	μA
Bushold input minimum drive hold current		I <sub>I (HOLD)</sub>	V <sub>IN</sub> = 0.36 V		1.8	25	—	μA
			V <sub>IN</sub> = 1.26 V		1.8	-25	—	
Bushold input over-drive current to change state		I <sub>I (OD)</sub>	(Note 1)		1.8	—	200	μA
			(Note 2)		1.8	—	-200	
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		1.8	—	±10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	—	20.0	μA

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

**AC Characteristics (Ta = -40 to 85°C, input:  $t_r = t_f = 2.0$  ns,  $C_L = 30$  pF,  $R_L = 500 \Omega$ ) (Note 1)**

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Maximum clock frequency	$f_{max}$	Figure 1, Figure 3	1.8	100	—	MHz
			$2.5 \pm 0.2$	200	—	
			$3.3 \pm 0.3$	250	—	
Propagation delay time (An, Bn-Bn, An)	$t_{pLH}$ $t_{pHL}$	Figure 1, Figure 2	1.8	1.5	7.0	ns
			$2.5 \pm 0.2$	0.8	3.5	
			$3.3 \pm 0.3$	0.6	2.9	
Propagation delay time (CAB, CBA-Bn, An)	$t_{pLH}$ $t_{pHL}$	Figure 1, Figure 3	1.8	1.5	8.8	ns
			$2.5 \pm 0.2$	0.8	4.4	
			$3.3 \pm 0.3$	0.6	3.2	
Propagation delay time (SAB, SBA-Bn, An)	$t_{pLH}$ $t_{pHL}$	Figure 1, Figure 2	1.8	1.5	8.8	ns
			$2.5 \pm 0.2$	0.8	4.4	
			$3.3 \pm 0.3$	0.6	3.5	
Output enable time (OEAB, $\overline{OEBA}$ -An, Bn)	$t_{pZL}$ $t_{pZH}$	Figure 1, Figure 4, Figure 5	1.8	1.5	9.8	ns
			$2.5 \pm 0.2$	0.8	4.9	
			$3.3 \pm 0.3$	0.6	3.8	
Output disable time (OEAB, $\overline{OEBA}$ -An, Bn)	$t_{pLZ}$ $t_{pHZ}$	Figure 1, Figure 4, Figure 5	1.8	1.5	8.1	ns
			$2.5 \pm 0.2$	0.8	4.5	
			$3.3 \pm 0.3$	0.6	3.9	
Minimum pulse width	$t_w(H)$ $t_w(L)$	Figure 1, Figure 3	1.8	4.0	—	ns
			$2.5 \pm 0.2$	1.5	—	
			$3.3 \pm 0.3$	1.5	—	
Minimum setup time	$t_s$	Figure 1, Figure 3	1.8	2.5	—	ns
			$2.5 \pm 0.2$	1.5	—	
			$3.3 \pm 0.3$	1.5	—	
Minimum hold time	$t_h$	Figure 1, Figure 3	1.8	1.0	—	ns
			$2.5 \pm 0.2$	1.0	—	
			$3.3 \pm 0.3$	1.0	—	
Output to output skew	$t_{osLH}$ $t_{osHL}$	(Note 2)	1.8	—	0.5	ns
			$2.5 \pm 0.2$	—	0.5	
			$3.3 \pm 0.3$	—	0.5	

Note 1: For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

## Dynamic Switching Characteristics

(Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Quiet output maximum dynamic VOL	VOLP	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	0.8	
Quiet output minimum dynamic VOL	VOLV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	-0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	-0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	-0.8	
Quiet output minimum dynamic VOH	VOHV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note)	1.8	1.5	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note)	2.5	1.9	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note)	3.3	2.2	

Note: Parameter guaranteed by design.

## Capacitive Characteristics (Ta = 25°C)

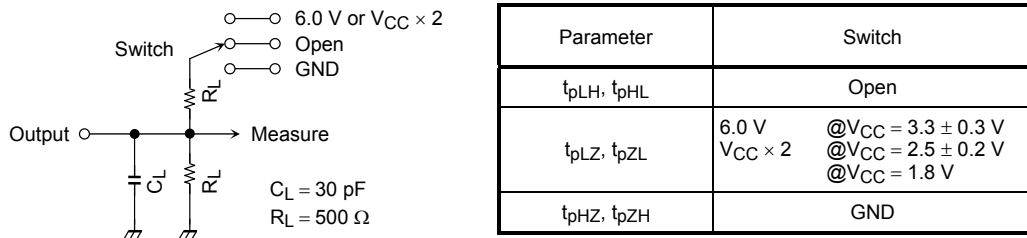
Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>	(OEAB, $\overline{OEBA}$ , CAB, CBA, SAB, SBA)	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C <sub>I/O</sub>	An, Bn	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note)	1.8, 2.5, 3.3	20	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

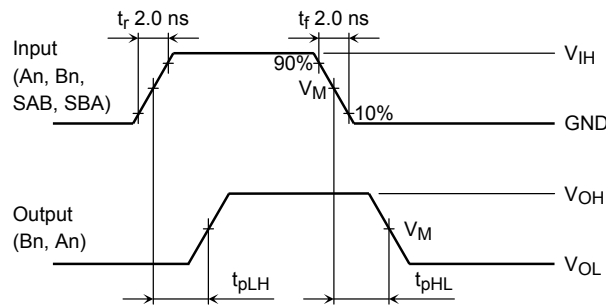
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$$

**AC Test Circuit**

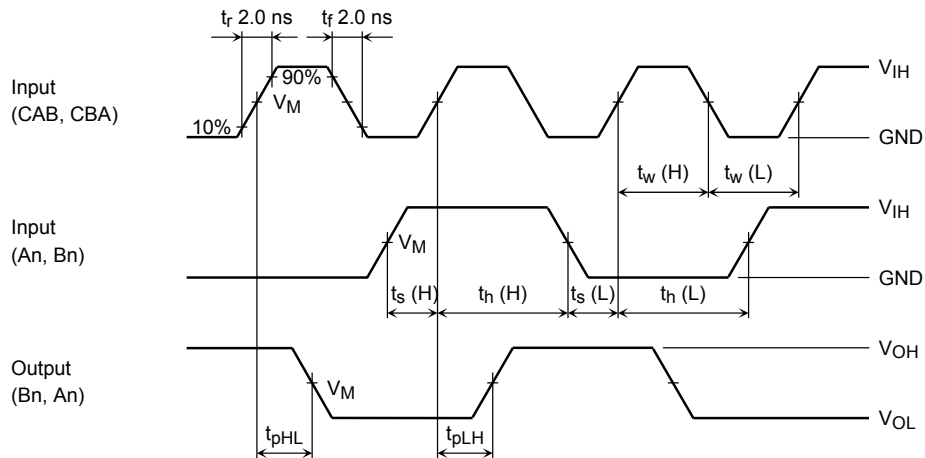


**Figure 1**

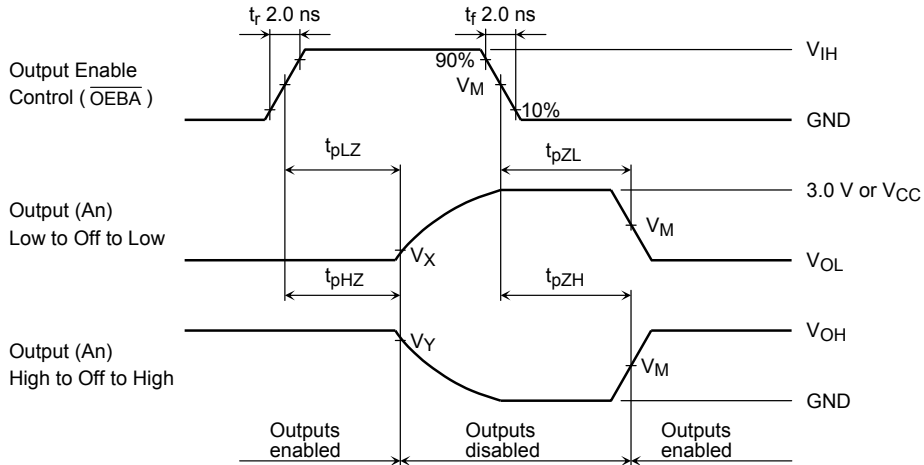
**AC Waveform**



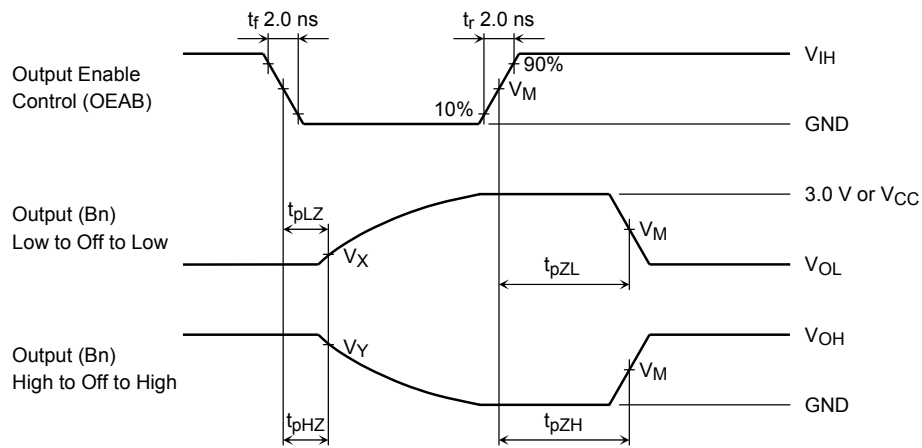
**Figure 2  $t_{pLH}, t_{pHL}$**



**Figure 3  $t_{pLH}, t_{pHL}, t_w, t_s, t_h$**



**Figure 4**  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$



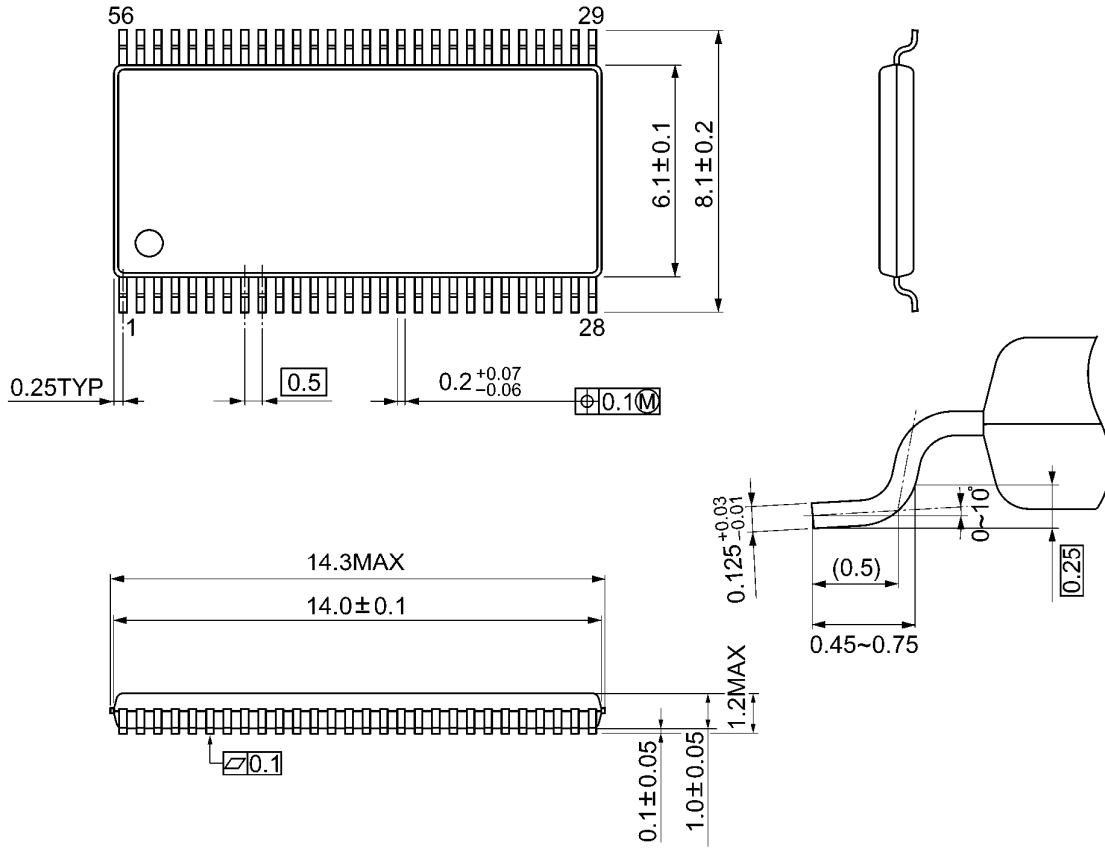
**Figure 5**  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$

Symbol	$V_{CC}$		
	$3.3 \pm 0.3$ V	$2.5 \pm 0.2$ V	1.8 V
$V_{IH}$	2.7 V	$V_{CC}$	$V_{CC}$
$V_M$	1.5 V	$V_{CC}/2$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3$ V	$V_{OL} + 0.15$ V	$V_{OL} + 0.15$ V
$V_Y$	$V_{OH} - 0.3$ V	$V_{OH} - 0.15$ V	$V_{OH} - 0.15$ V

## Package Dimensions

TSSOP56-P-0061-0.50A

Unit: mm



Weight: 0.25 g (typ.)

**RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
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In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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